



JRW

PATENT APPLICATION

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Izumi FUSEGAWA et al.

Group Art Unit: 1722

Application No.: 10/568,186

Examiner: F. HITESHEW

Filed: February 13, 2006

Docket No.: 126961

For: METHOD FOR PRODUCING A SINGLE CRYSTAL AND SILICON SINGLE CRYSTAL WAFER

REQUEST FOR RECONSIDERATION

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

In reply to the June 11, 2007 Office Action, please consider the following:

Remarks.